



# Electro Optical Components, Inc.

5460 Skyline Boulevard, Santa Rosa, CA 95403

Toll Free: 855-EOC-6300

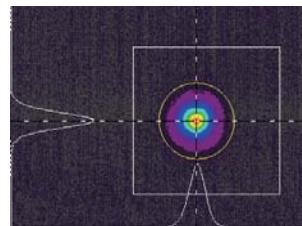
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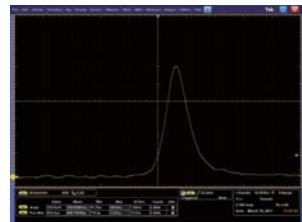
## 1064nm Sub-nanosecond DPSS Laser



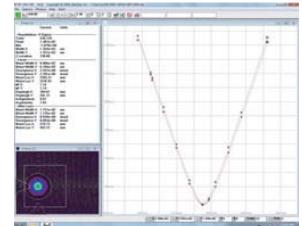
The 1064nm Sub-nanosecond Laser is based on a passively Q-switched DPSS laser with pulse length of only a few hundred picoseconds. The high pulse energy and excellent beam quality make it an ideal choice for industrial and scientific applications. The pump diode module is integrated in the power supply. The laser can be operated from external or internal trigger mode.



Beam profile



Typical Pulse



$M^2 < 1.2$

### Key Features

- Pulse width<1ns (Min<200ps);
- Pulse energy 10-100uJ (Max>3mJ);
- Peak power up to 100kW;
- Internal and external trigger mode (repetition rate less than 10kHz);
- High repetition rate up to 100 kHz.

### Standard Wavelengths

1064nm

### Applications

Super-continuum generation	Seed light source
Raman spectroscopy	Ranging
LIDAR	3D Scanning
3D Imaging	Bio-photonic
Micromachining	Atmospheric detection

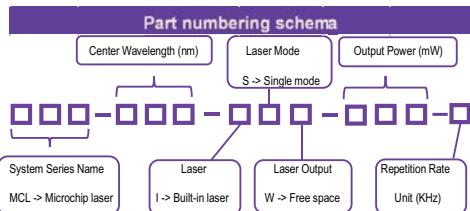
Optical parameters									
Wavelength (nm)	1064								
Repetition rate(kHz)	0.5	1	5	10	20				
Pulse width(ns)	1	0.6	0.6	0.9	0.8				
Average output power(mW)	80	100	200	200	200				
Pulse energy(μJ)	160	100	40	20	10				
Short term power stability (1min)	$\leq 1\%$								
Long term power stability (8hrs)	$\pm 3\%$								
Beam profile	TEM00								
Full angle divergence (mrad)	Horizontal @ $1/e^2$	typ.5							
	Vertical @ $1/e^2$	typ.5							
$M^2$	<1.2								
Polarization (dB)	>100:1								
System parameters									
Power supply voltage	100-240V,50/60 Hz								
Modulation input	TTL								
Control interface	Serial Interface								
Power consumption	<50W								
Storage humidity	0~80%RH								
Power dimensions (W×H×L, mm)	250×100×300								
Laser head dimensions (W×H×L, mm)	45×25×78								
Operating temperature	15-35°C								
Storage temperature	0-50°C								

Note: Above 2 kHz more than one amplitudes with 10-20% jumps due to intrinsic laser dynamics may appear.

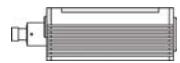
## Ordering information

MCL Series Model List			
Wavelength	Power	Part number	Repetition rate
1064nm	80mW	MCL-1064-ISW-080-0.5	0.5KHz
	100mW	MCL-1064-ISW-100-1	1KHz
	200mW	MCL-1064-ISW-200-5	5KHz
	200mW	MCL-1064-ISW-200-10	10KHz
	200mW	MCL-1064-ISW-200-20	20KHz

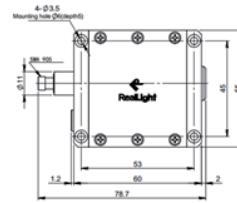
## Part numbering schema



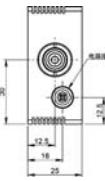
## Mechanical Specifications



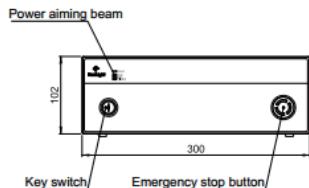
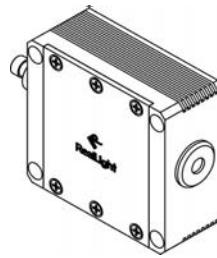
Laser Left View



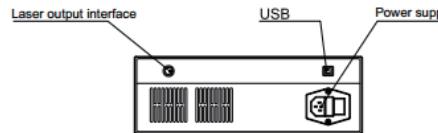
## Laser Top View



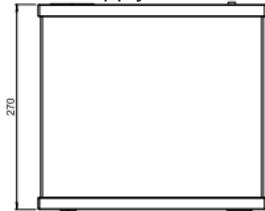
Laser Front View



## Power Supply Front View



## Power Supply Back View



## Power Supply Top View



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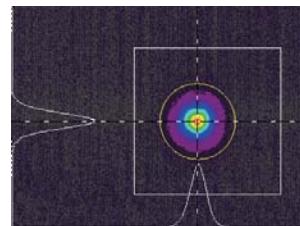
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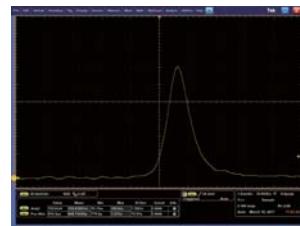
## 532nm Sub-nanosecond DPSS Laser



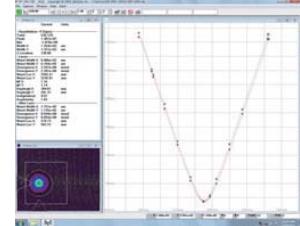
The 532nm Sub-nanosecond Laser is based on a passively Q-switched DPSS laser with pulse length of only a few hundred picoseconds. The high pulse energy and excellent beam quality make it an ideal source for industrial and scientific applications. The pump diode module is integrated in the power supply. The laser can be operated from external or internal trigger mode.



Beam profile



Typical Pulse



$M^2 < 1.2$

### Key Features

- Pulse width<1ns (Min<200ps);
- Pulse energy 10-80μJ (Max>2mJ);
- Peak power up to 100kW;
- Internal and external trigger mode (repetition rate less than 10kHz);
- High repetition rate up to 100 kHz;

### Standard Wavelengths

532nm

### Applications

Raman spectroscopy	Mass spectrograph
Atmospheric detection	LIDAR
Non-linear optics	Biohazard detection
Micromachining	Two-photon microscopy
Laser Induced Fluorescence	

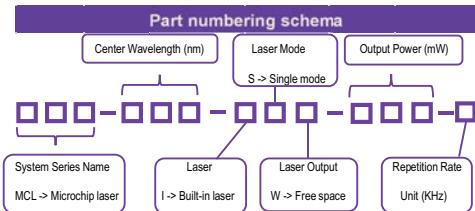
Optical parameters				
Wavelength (nm)	532			
Repetition rate(kHz)	0.5	1	5	10
Pulse width(ns)	0.8	0.5	0.5	0.7
Average output power(mW)	40	50	100	100
Pulse energy(μJ)	80	50	20	10
Short term power stability (1min)	≤1%			
Long term power stability (8hrs)	±3%			
Beam profile	TEM00			
$M^2$	<1.3			
Polarization (dB)	>100:1			
System parameters				
Power supply voltage	100-240V,50/60Hz			
Modulation input	TTL			
Control interface	USB2.0.Serial Interface			
Power consumption	<50W			
Storage humidity	0-80%RH			
Power dimensions (W×H×L, mm)	250×100×300			
Laser head dimensions (W×H×L, mm)	45×25×78			
Operating temperature	15-35°C			
Storage temperature	0-50°C			

Note: Above 2 kHz more than one amplitudes with 10-20% jumps due to intrinsic laser dynamics may appear.

### Ordering information

MCL Series Model List			
Wavelength	Power	Part number	Repetition rate
532nm	40mW	MCL-532-ISW-040-0.5	0.5KHz
	50mW	MCL-532-ISW-050-1	1KHz
	100mW	MCL-532-ISW-100-5	5KHz
	100mW	MCL-532-ISW-100-10	10KHz

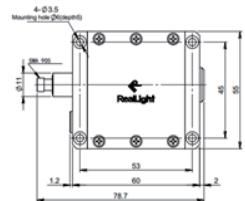
### Part numbering schema



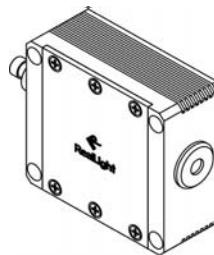
### Mechanical Specifications



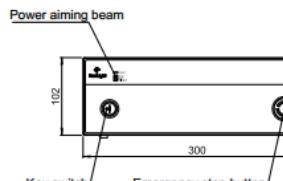
Laser Left View



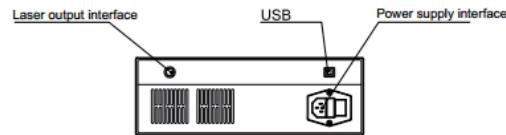
Laser Top View



Laser Front View



Power Supply Front View



Power Supply Back View



Unit: mm

Power Supply Top View